

January 9, 1998

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## HIGH VOLTAGE, HIGH DENSITY, STANDARD RECOVERY MODULAR RECTIFIER ASSEMBLY

- Low forward voltage drop
- Low reverse leakage current
- High thermal shock resistance
- Modular construction and design versatility
- Low distributed capacitance

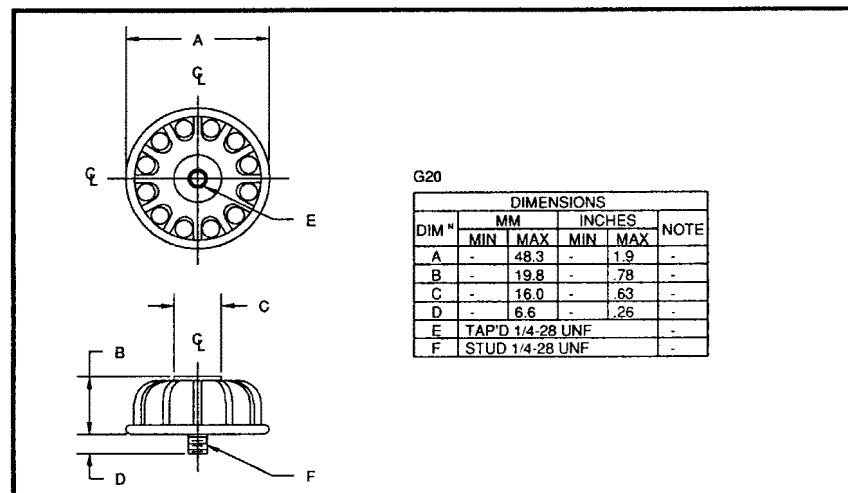
## QUICK REFERENCE DATA

- $V_R = 2500 - 10000V$
- $I_F = 1.2 - 4.0A$  (in air)
- $I_R = 1 - 3 \mu A$  (max)
- $t_{rr} = 2.5\mu s$

## ABSOLUTE MAXIMUM RATINGS

Device Type	Working Reverse Voltage $V_{RWM}$	Average Rectified Current $I_{F(AV)}$				1 Cycle Surge Current $I_{FSM}$ $t_p = 8.3mS$		Repetitive Surge Current $I_{FRM}$ @ 25°C	$I^2t$ $t_p = 8.3mS$ @ 25°C
		Air @ 25°C	Air @ 100°C	Stud to Heatsink @ 25°C	Still oil @ 55°C	@ 25°C	@ 100°C		
		Volts	Amps	Amps	Amps	Amps	Amps	Amps	A <sup>2</sup> S
S3HVM2.5	2500	3.0	1.25	3.0	3.0	50	20	11	10
S3HVM5	5000	2.4	1.0	3.0	3.0	50	20	11	10
S3HVM7.5	7500	1.5	0.63	3.0	3.0	50	20	11	10
S3HVM10	10000	1.2	0.5	2.5	3.0	50	20	11	10
S6HVM2.5	2500	4.0	1.5	6.0	6.0	100	40	22	41.5
S6HVM5	5000	2.4	1.0	6.0	6.0	100	40	22	41.5
S9HVM2.5	2500	5.0	1.8	7.5	10.0	150	60	33	93.3

## MECHANICAL



### MAXIMUM THERMAL IMPEDANCES

Junction - Ambient  $R_{\theta JA} < 12^\circ C/W$   
 Junction - Stud  $R_{\theta JS} < 6^\circ C/W$   
 Junction - Oil  $R_{\theta JO} < 4.5^\circ C/W$

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## ELECTRICAL CHARACTERISTICS

Device Type	Maximum Reverse Leakage Current $I_R @ V_{RWM}$		Maximum Forward Voltage $V_F @ 25^\circ\text{C}$	Maximum Reverse Recovery Time <sup>1</sup> $t_{rr} @ 25^\circ\text{C}$
	@ 25 °C	@ 100 °C		
	μA	μA	Volts	μS
S3HVM2.5	1.0	10.0	3.45 @ 3.0A	<div style="display: flex; align-items: center; justify-content: center;"> <div style="border-left: 1px solid black; border-right: 1px solid black; height: 100px; margin: 0 5px;"></div> <span style="font-size: 2em;">2.5</span> </div>
S3HVM5	1.0	10.0	5.75	
S3HVM7.5	1.0	10.0	9.20	
S3HVM10	1.0	10.0	11.5	
S6HVM2.5	2.0	20.0	3.45 @ 6.0A	
S6HVM5	2.0	20.0	5.75	
S9HVM2.5	3.0	30.0	3.45 @ 9.0A	
			3.45	

1. Measured on discrete devices prior to assembly

Operating temperature range -55 °C to +150 °C  
Storage temperature range -55 °C to +150 °C

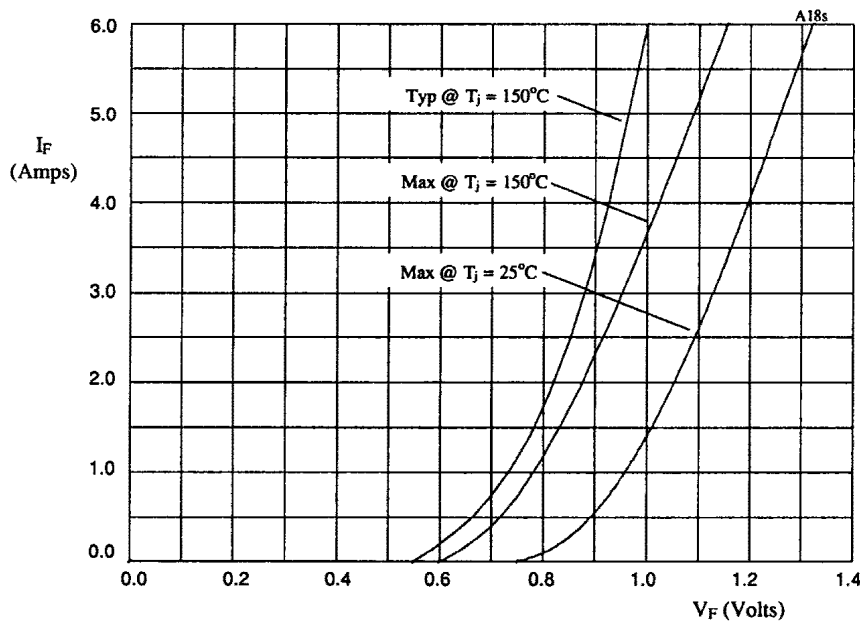


Figure 1. Forward voltage drops as a function of forward current for use with table 1.

TABLE I

DEVICE	X-axis	Y-axis
S3HVM2.5	x3	x1
S3HVM5	x5	x1
S3HVM7.5	x8	x1
S3HVM10	x10	x1
S6HVM2.5	x3	x2
S6HVM5	x5	x2
S9HVM2.5	x3	x3